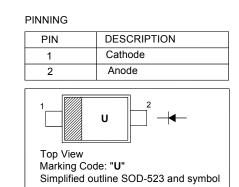
SILICON BAND SWITCHING DIODE

Applications

for band switching in VHF television tuners and surface mount band switching circuits



Absolute Maximum Ratings (T_a = 25 °C)

Parameter	Symbol	Value	Unit
Reverse Voltage	V _R	35	V
Forward Current	I _F	100	mA
Junction Temperature	TJ	150	°C
Operating Temperature Range	T _{op}	- 55 to + 125	°C
Storage Temperature Range	T _{stg}	- 55 to + 150	°C

Characteristics at $T_a = 25 \ ^{\circ}C$

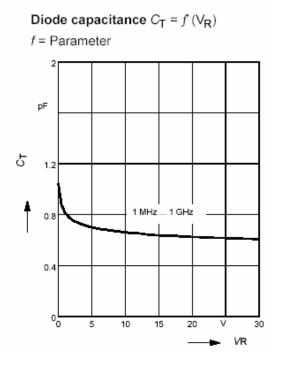
Parameter	Symbol	Min.	Тур.	Max.	Unit
Reverse Current at V_R = 20 V	I _R	-	-	20	nA
Forward Voltage at I _F = 100 mA	V _F	-	-	1	V
Diode Capacitance at $V_R = 1 V$, f = 1 MHz at $V_R = 3 V$, f = 1 MHz at $V_R = 0 V$, f = 100 MHz	CT	0.65 0.6 -	- - 1	1.4 1.1 -	pF
Forward Resistance at $I_F = 3 \text{ mA}$, f = 100 MHz at $I_F = 10 \text{ mA}$, f = 100 MHz	r _f	-	-	0.7 0.5	Ω
Series Inductance	Ls	-	0.6	-	nH



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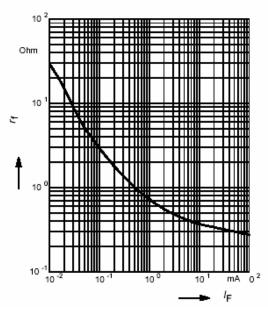


Dated : 23/11/2006

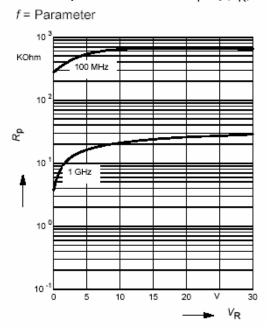


Forward resistance $r_{\rm f} = f (I_{\rm F})$

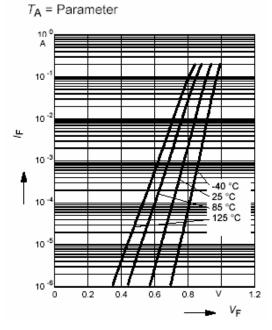
f = 100MHz



Reverse parallel resistance $R_{\rm P} = f(V_{\rm R})$



Forward current $I_F = f(V_F)$









Dated : 23/11/2006

PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

ALL ROUND ∢ H_E D -(A) q ш С Е V UNIT D H_{E} А bp _ 0.70 0.4 0.135 1.25 0.85 1.7 0.1 5° mm 0.60 0.3 0.75 1.5 0.127 1.15



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